Fast Recovery Diodes (Stud Version), 6 A, 12 A, 16 A

DO-203AA (DO-4)

FEATURES

- Short reverse recovery time
- Low stored charge
- Wide current range
- Excellent surge capabilities
- Standard JEDEC types
- Stud cathode and stud anode versions
- Fully characterized reverse recovery conditions
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

RoHS COMPLIANT

TYPICAL APPLICATIONS

- DC power supplies
- Inverters
- Converters
- Choppers
- Ultrasonic systems
- Freewheeling diodes

PRODUCT SUMMARY	
$I_{F(AV)}$	6 A, 12 A, 16 A

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	6FL..	12FL..	16FL..	UNITS
$I_{F(AV)}$	T_C = 100 °C	6	12	16	A
$I_{F(RMS)}$		9.5	19	25	A
I_{FSM}	50 Hz	110	145	180	A
	60 Hz	115	150	190	
I^2t	50 Hz	60	103	160	A^2s
	60 Hz	55	94	150	
$I^2\sqrt{t}$		1452	1452	2290	$I^2\sqrt{s}$
V_{RRM}	Range	50 to 1000			V
t_{rr}		See Recovery Characteristics table			ns
T_J	Range	- 65 to 150			°C

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ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS

TYPE NUMBER	VOLTAGE CODE	V_{RRM}, MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V_{RSM}, MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	I_{RRM} MAXIMUM AT T_J = 25 °C µA	I_{RRM} MAXIMUM AT T_J = 100 °C mA	I_{RRM} MAXIMUM AT T_J = 150 °C mA
6FL.. 12FL.. 16FL..	5	50	75	50	-	6.0
	10	100	150			
	20	200	275			
	40	400	500			
	60	600	725			
	80	800	950			
	100	1000	1250			

FORWARD CONDUCTION

PARAMETER	SYMBOL	TEST CONDITIONS			6FL..	12FL..	16FL..	UNITS
Maximum average forward current at case temperature	$I_{F(AV)}$	180° conduction, half sine wave DC			6	12 (1)	16	A
					100	100	100	°C
Maximum RMS current	$I_{F(RMS)}$				9.5	19	25	A
Maximum peak, one-cycle non-repetitive forward current	I_{FSM}	t = 10 ms	No voltage reapplied	Sinusoidal half wave, initial T_J = 150 °C	130	170	215	
		t = 8.3 ms			135	180	225	
		t = 10 ms	100 % V_{RRM} reapplied		110	145	180	
		t = 8.3 ms			115	150 (1)	190	
Maximum I^2t for fusing	I^2t	t = 10 ms	No voltage reapplied		86	145	230	A^2s
		t = 8.3 ms			78	130	210	
		t = 10 ms	100 % V_{RRM} reapplied		60	103	160	
		t = 8.3 ms			55	94	150	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	t = 0.1 ms to 10 ms, no voltage reapplied			856	1452	2290	$A^2\sqrt{s}$
Maximum forward voltage drop	V_{FM}	T_J = 25 °C; I_F = Rated $I_{F(AV)}$ (DC)			1.4	1.4 (1)	1.4	V
		T_C = 100 °C; I_{FM} = π x rated $I_{F(AV)}$			1.5	1.5 (1)	1.5	

Note

(1) JEDEC registered values

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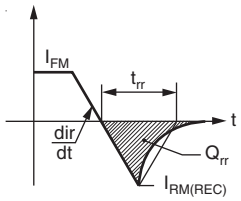
RECOVERY CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS	6FL.. 12FL.. 16FL..		UNITS	
			S02	S05		
Maximum reverse recovery time	t_{rr}	T_J = 25 °C, I_F = 1 A to V_R = 30 V, dI_F/dt = 100 A/µs	-	-	ns	
		T_J = 25 °C, dI_F/dt = 25 A/µs, I_{FM} = π x rated $I_{F(AV)}$	200	500		
Maximum peak recovery current	$I_{RM(REC)}$	I_{FM} = π x rated $I_{F(AV)}$	-		-	
Maximum reverse recovery charge	Q_{rr}	T_J = 25 °C, I_F = 1 A to V_R = 30 V, dI_F/dt = 100 A/µs	-	-	nC	
		T_J = 25 °C, dI_F/dt = 25 A/µs, I_{FM} = π x rated $I_{F(AV)}$	-	-		

Note

(1) JEDEC registered values

THERMAL AND MECHANICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS	6FL..	12FL..	16FL..	UNITS
Maximum junction operating temperature range	T_J		- 65 to 150			°C
Maximum storage temperature range	T_{Stg}		- 65 to 175			
Maximum thermal resistance, junction to case	R_{thJC}	DC operation	2.5	2.0	1.6	°C/W
Maximum thermal resistance, case to heatsink	R_{thCS}	Mounting surface, smooth, flat and greased	0.5			
Allowable mounting torque		Not lubricated threads	$1.5^{+0-10\%}$ (13)			N · m (lbf · in)
		Lubricated threads	$1.2^{+0-10\%}$ (10)			
Approximate weight			7			g
			0.25			oz.
Case style		JEDEC	DO-203AA (DO-4)			

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ΔR_{thJC} CONDUCTION								
CONDUCTION ANGLE	6FL..	12FL..	16FL..	6FL..	12FL..	16FL..	TEST CONDITIONS	UNITS
	SINUSOIDAL CONDUCTION			RECTANGULAR CONDUCTION				
180°	0.58	0.46	0.37	0.33	0.26	0.21	T_J = 150 °C	K/W
120°	0.60	0.48	0.39	0.58	0.46	0.37		
60°	1.28	1.02	0.82	1.28	1.02	0.82		
30°	2.20	1.76	1.41	2.20	1.76	1.41		

Note

- The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

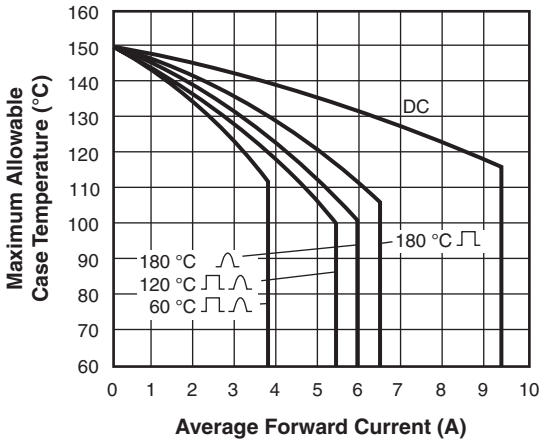


Fig. 1 - Average Forward Current vs.
Maximum Allowable Case Temperature, 6FL Series

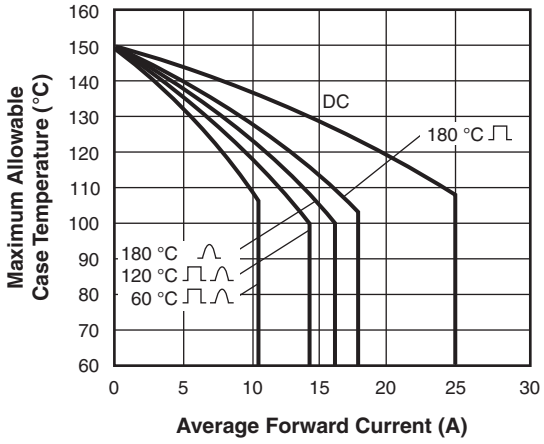


Fig. 3 - Average Forward Current vs.
Maximum Allowable Case Temperature, 16FL Series

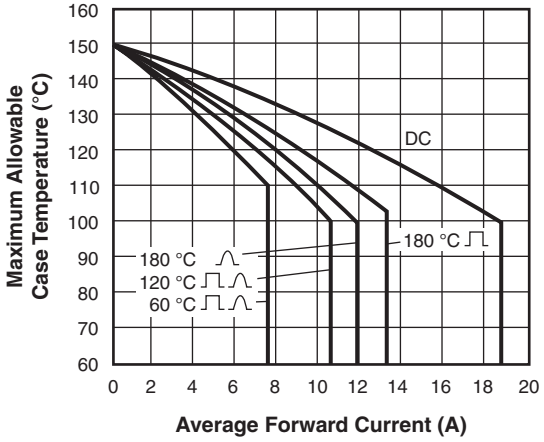
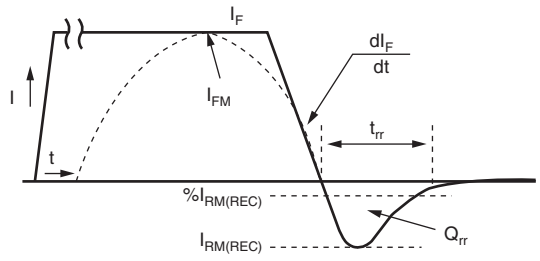


Fig. 2 - Average Forward Current vs.
Maximum Allowable Case Temperature, 12FL Series



I_F, I_{FM} - Peak forward current prior to commutation
$-dI_F/dt$ - Rate of fall of forward current
$I_{RM(REC)}$ - Peak reverse recovery current
t_{rr} - Reverse recovery time
Q_{rr} - Reverse recovered charge

Fig. 4 - Reverse Recovery Time Test Waveform

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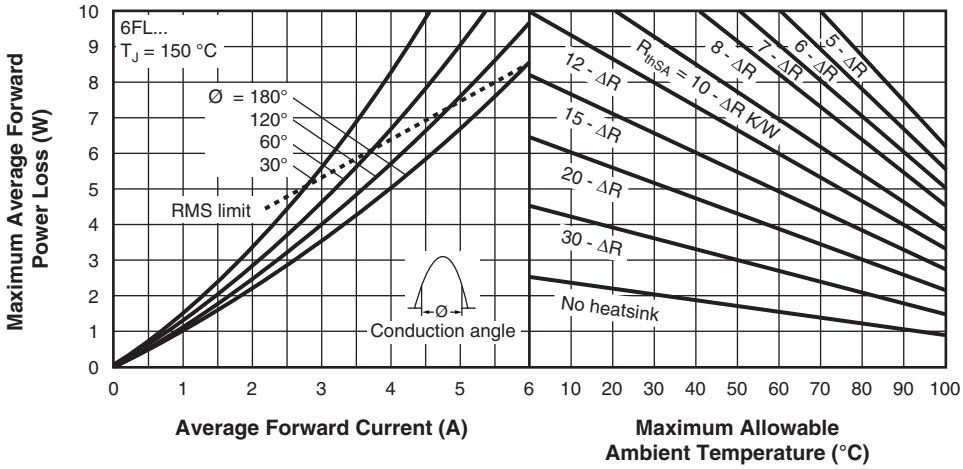
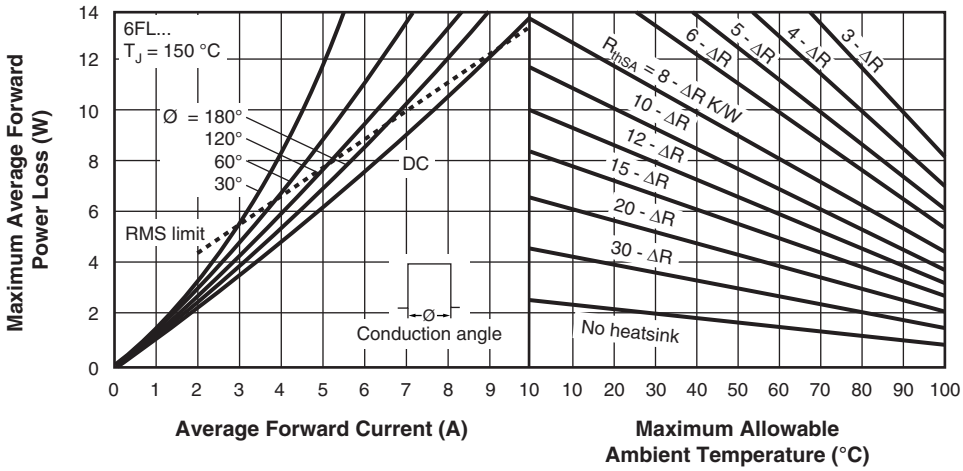


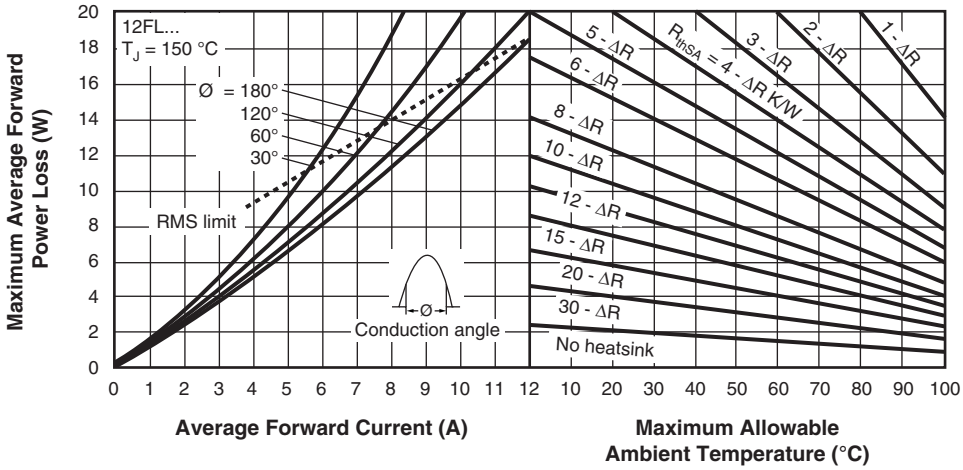
Conduction angle - Ø	ΔR - K/W
180°	0.58
120°	0.60
60°	1.28
30°	2.20

Fig. 5 - Current Rating Nomogram (Sinusoidal Waveforms), 6FL Series



Conduction angle - Ø	ΔR - K/W
DC	0
180°	0.33
120°	0.58
60°	1.28
30°	2.20

Fig. 6 - Current Rating Nomogram (Rectangular Waveforms), 6FL Series



Conduction angle - Ø	ΔR - K/W
180°	0.46
120°	0.48
60°	1.02
30°	1.76

Fig. 7 - Current Rating Nomogram (Sinusoidal Waveforms), 12FL Series

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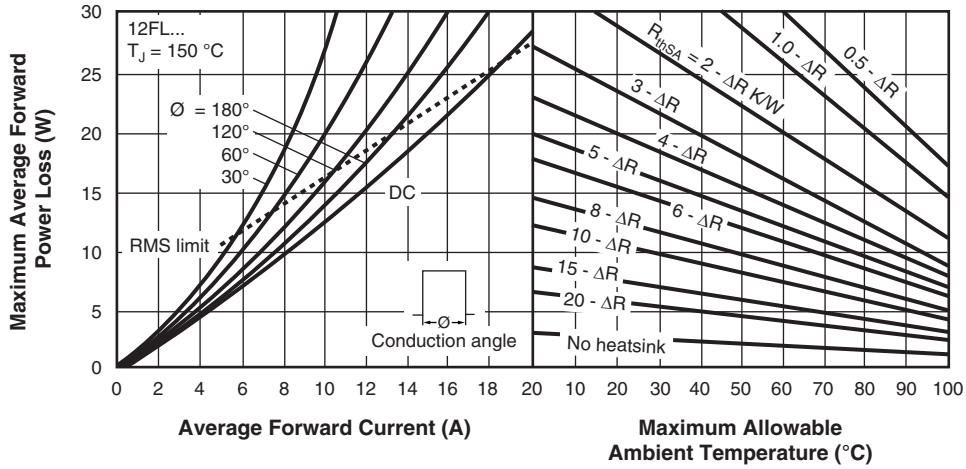
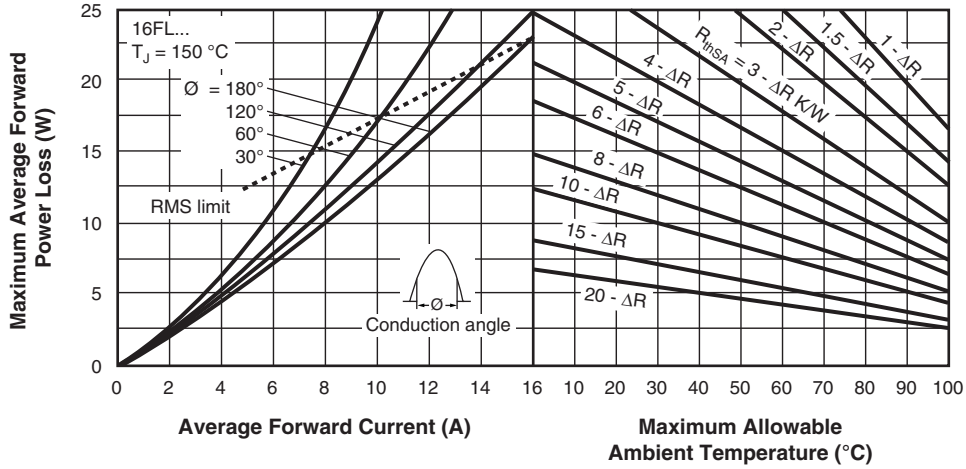


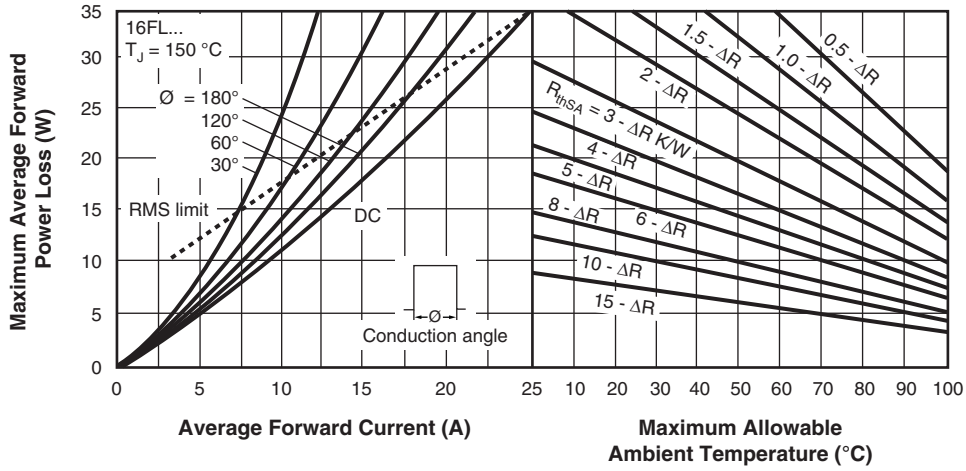
Conduction angle - Ø	ΔR - K/W
DC	0
180°	0.26
120°	0.46
60°	1.02
30°	1.76

Fig. 8 - Current Rating Nomogram (Rectangular Waveforms), 12FL Series



Conduction angle - Ø	ΔR - K/W
180°	0.37
120°	0.39
60°	0.82
30°	1.41

Fig. 9 - Current Rating Nomogram (Sinusoidal Waveforms), 16FL Series



Conduction angle - Ø	ΔR - K/W
DC	0
180°	0.21
120°	0.37
60°	0.82
30°	1.41

Fig. 10 - Current Rating Nomogram (Rectangular Waveforms), 16FL Series

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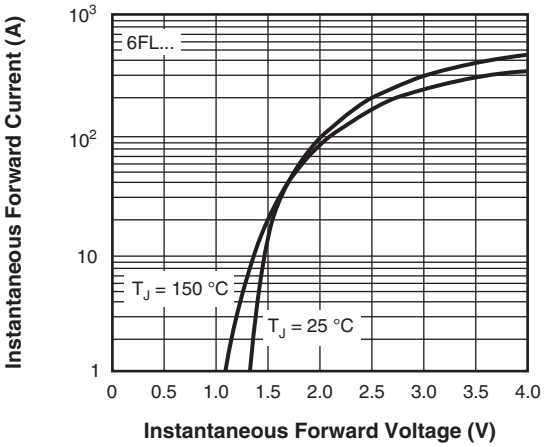

Fig. 11 - Maximum Forward Voltage vs. Forward Current, 6FL Series

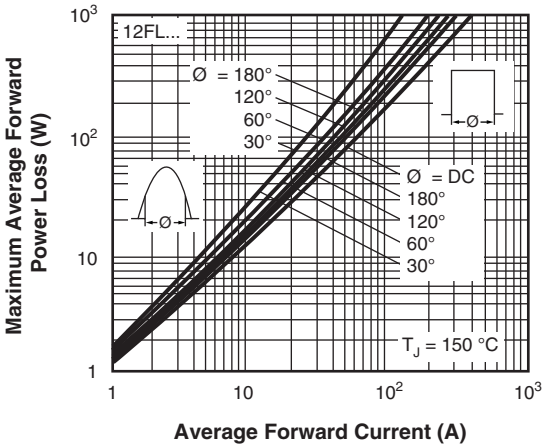

Fig. 14 - Maximum High Level Forward Power Loss vs. Average Forward Current, 12FL Series

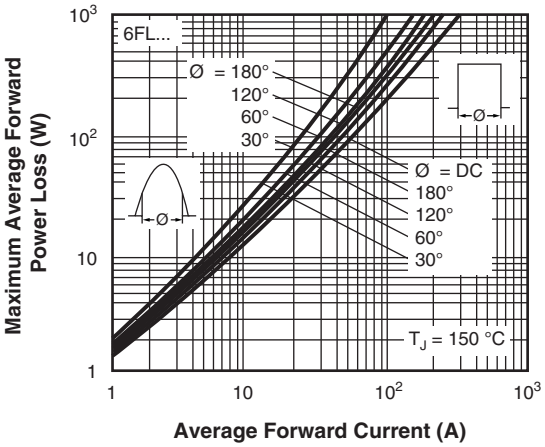

Fig. 12 - Maximum High Level Forward Power Loss vs. Average Forward Current, 6FL Series

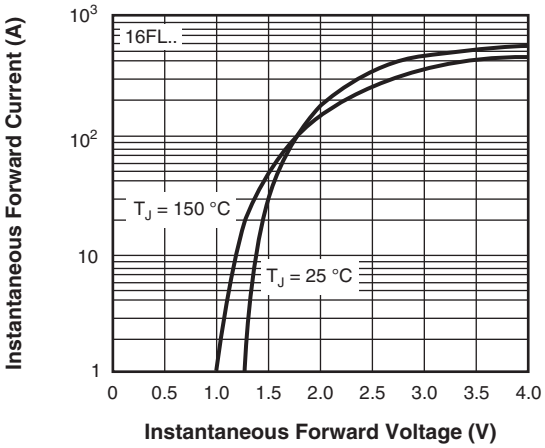

Fig. 15 - Maximum Forward Voltage vs. Forward Current, 16FL Series

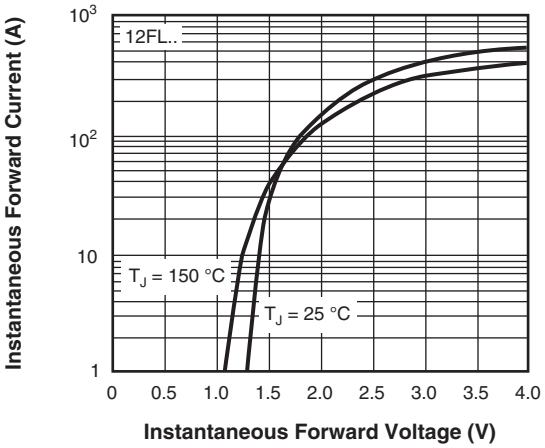

Fig. 13 - Maximum Forward Voltage vs. Forward Current, 12FL Series

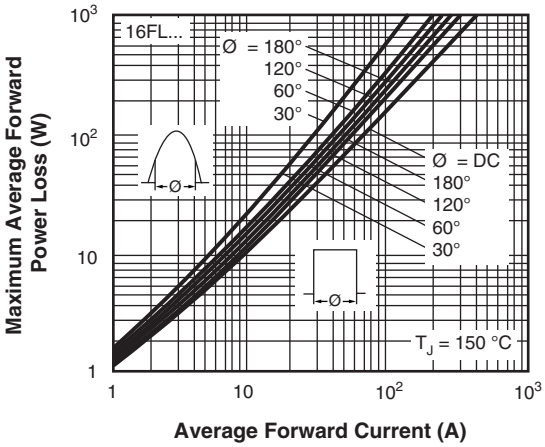

Fig. 16 - Maximum High Level Forward Power Loss vs. Average Forward Current, 16FL Series

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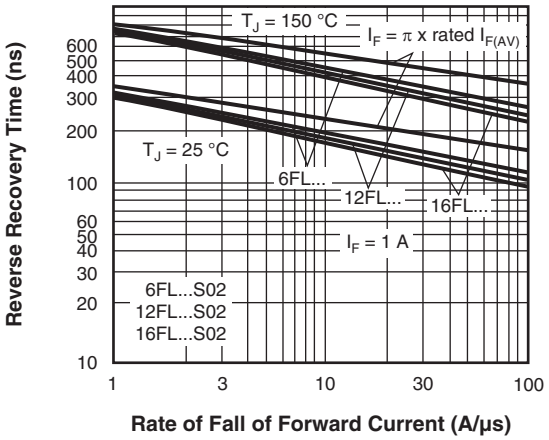

Fig.17a - Typical Reverse Recovery Time vs.
Rate of Fall of Forward Current, All Series ...S02

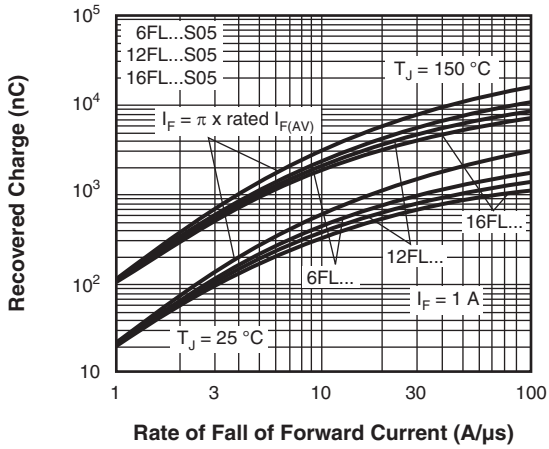

Fig. 18b - Typical Recovered Charge vs.
Rate of Fall of Forward Current, All Series ...S05

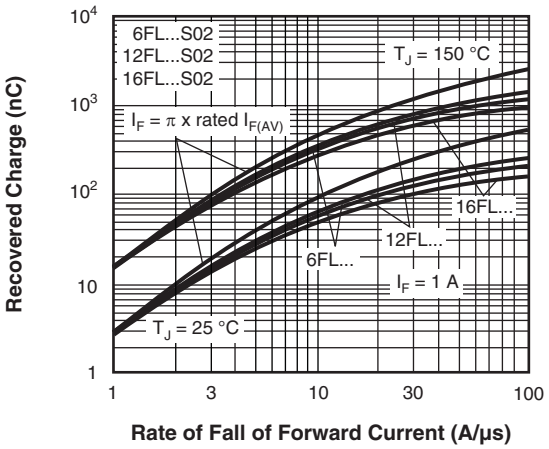

Fig. 17b - Typical Recovered Charge vs.
Rate of Fall of Forward Current, All Series ...S02

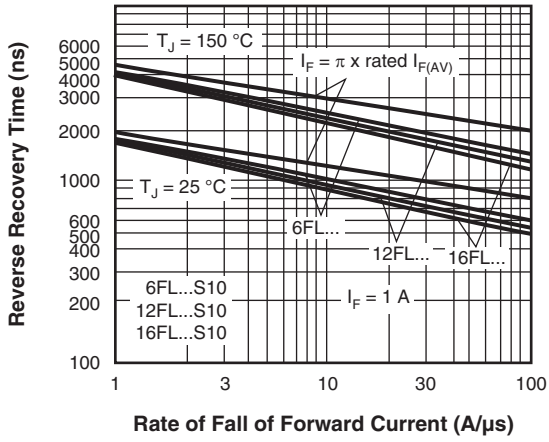

Fig. 19a - Typical Reverse Recovery Time vs.
Rate of Fall of Forward Current, All Series ...S10

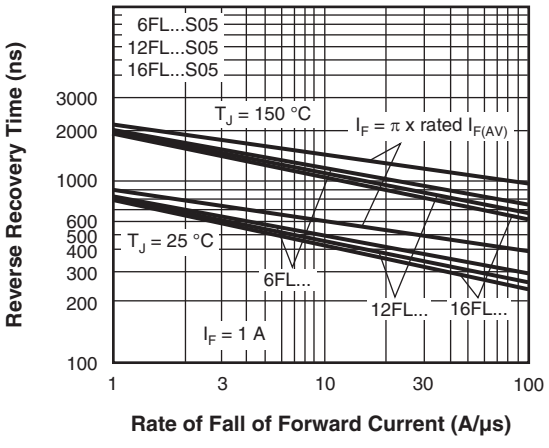

Fig. 18a - Typical Reverse Recovery Time vs.
Rate of Fall of Forward Current, All Series ...S05

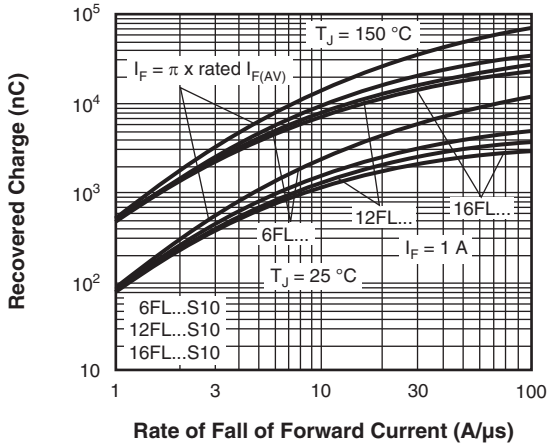

Fig. 19b - Typical Recovered Charge vs.
Rate of Fall of Forward Current, All Series ...S10

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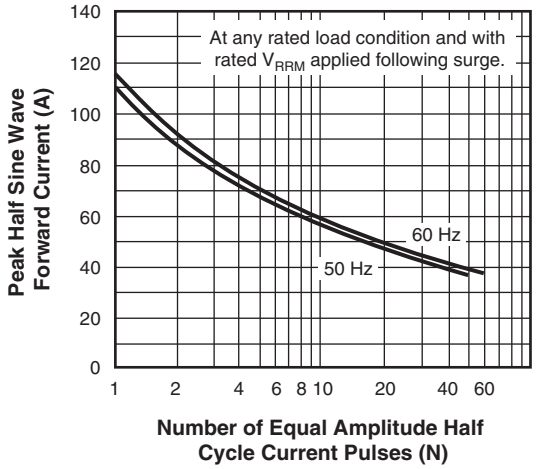

Fig. 20 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 6FL Series

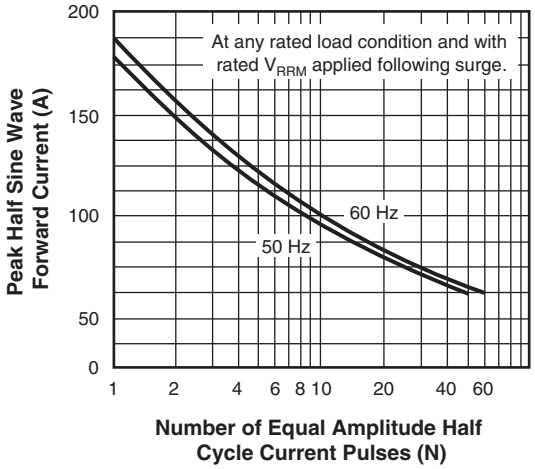

Fig. 22 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 16FL Series

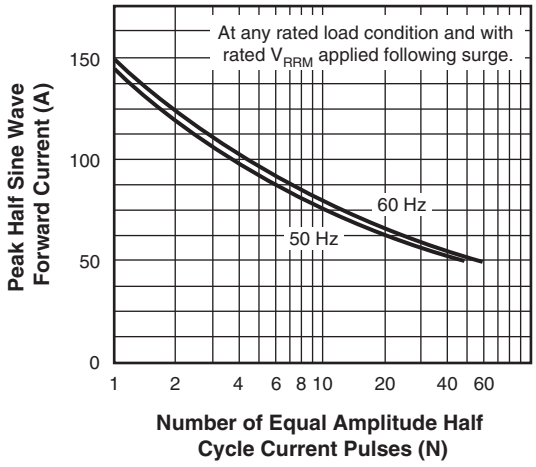

Fig. 21 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 12FL Series

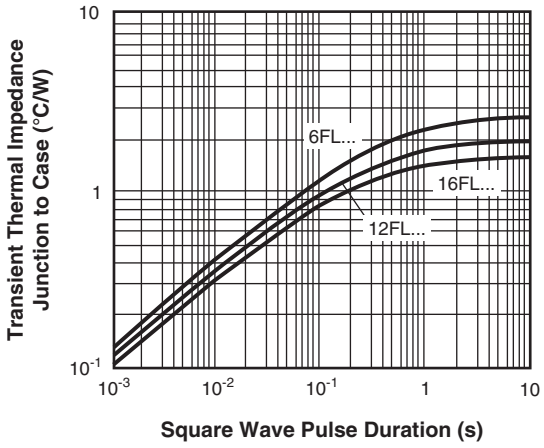

Fig. 23 - Maximum Transient Thermal Impedance, Junction to Case vs. Pulse Duration, All Series

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ORDERING INFORMATION TABLE

Device code

16	F	L	R	60	M	S02
1	2	3	4	5	6	7

1 - Current code $I_{(AVG)}$ = Exact current rating

2 - F = Diode

3 - Omit = Standard recovery diode
L = Only for fast diode

4 - Omit = Stud forward polarity
R = Stud reverse polarity

5 - Voltage code x 10 = V_{RRM} (see Voltage Ratings table)

6 - Outlines:
Omit = Stud base UNF thread
M = Stud base metric thread

7 - t_{rr} code only for fast diode (see Recovery Characteristics table)

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95311

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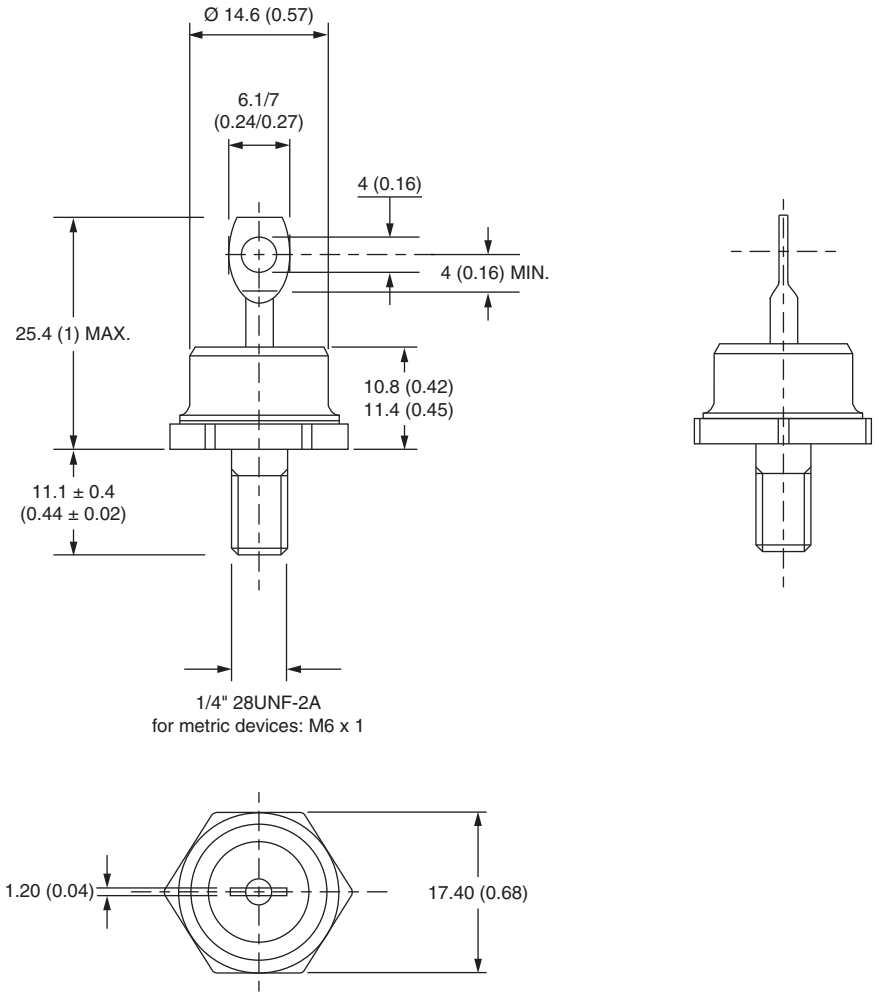
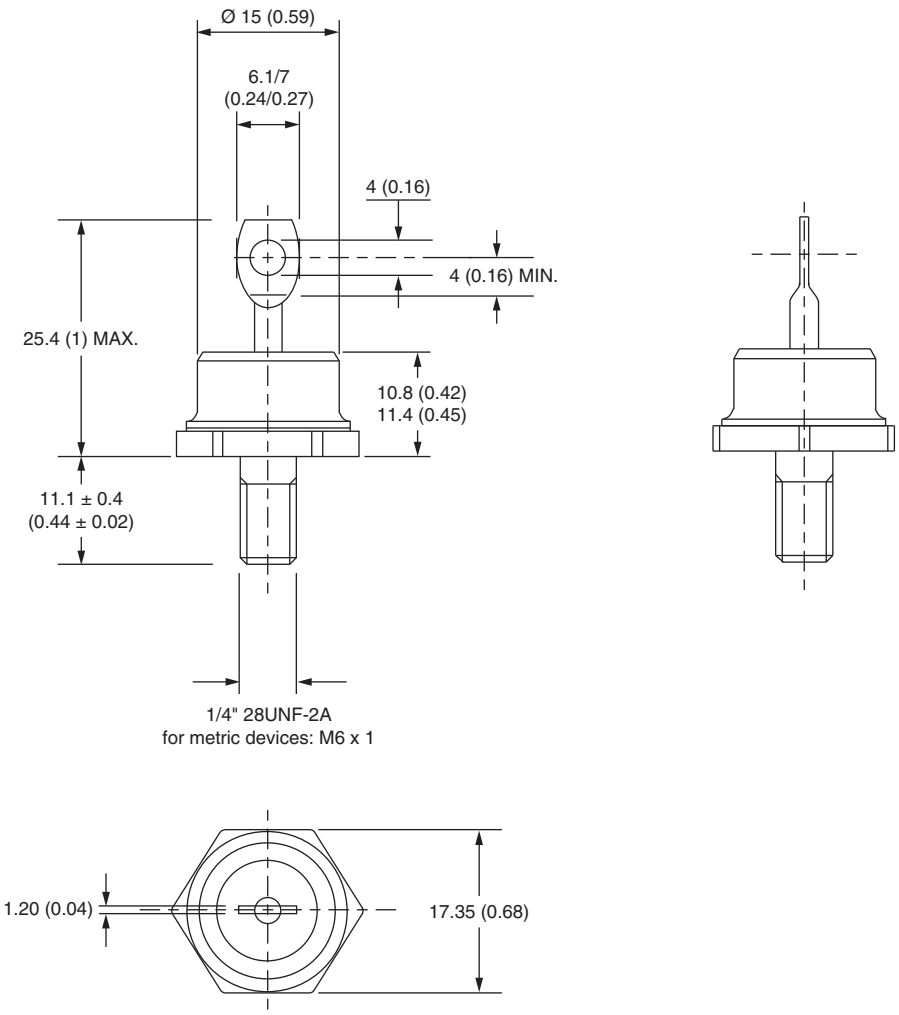
DO-203AB (DO-5) for 40HFL, 70HFL and 85HFL

DIMENSIONS FOR 40HFL/70HFL in millimeters (inches)



DIMENSIONS FOR 85HFL in millimeters (inches)



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